

isc Silicon NPN Power Transistor

2N6738

DESCRIPTION

- Collector-Emitter Sustaining Voltage-
- : V_{CEO(SUS)} = 300V(Min)
- High Switching Speed
- Low Saturation Voltage
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

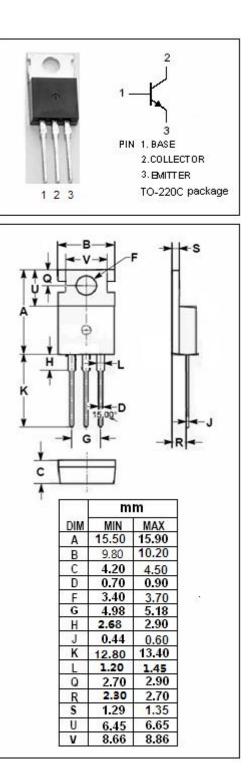
• Designed for use in high-voltage, high-speed, power switching in inductive circuit, they are particularly suited for 115 and 220V switchmode applications such as switching regulators, inverters, DC-DC and converter.

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)				
SYMBOL	PARAMETER	VALUE	UNIT	
VCEV	Collector-Emitter Voltage-V _{BE} = -1.5V	450	V	
VCEX	Collector-Emitter Voltage-V _{BE} = -1.5V	350	V	
Vceo	Collector-Emitter Voltage	300	V	
V _{EBO}	Emitter-Base Voltage	8	V	
lc	Collector Current-Continuous	8	А	
I _{CM}	Collector Current-Peak	10	А	
IB	Base Current-Continuous	4	А	
Pc	Collector Power Dissipation Tc=25℃	100	W	
Tj	Junction Temperature	150	°C	
T _{stg}	Storage Ttemperature Range	-65~150	°C	

ABSOLUTE MAXIMUM RATINGS(Ta=25℃

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT
R _{th j-c}	Thermal Resistance, Junction to Case		℃/W



isc website: www.iscsemi.com



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ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V _{CEO(SUS)}	Collector-Emitter Sustaining Voltage	I _C = 50mA; I _B = 0	300		V
V _{CE(sat)-1}	Collector-Emitter Saturation Voltage	I _C = 5A; I _B = 1A		1	V
V _{CE(sat)-2}	Collector-Emitter Saturation Voltage	I _C = 8A; I _B = 4A		2	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 5Α; I _B = 1Α		1.6	V
I _{EBO}	Emitter Cutoff Current	V _{EB} = 8V; I _C = 0		2	mA
h _{FE}	DC Current Gain	Ic= 5A ; Vce= 3V	10	40	
fT	Current-Gain—Bandwidth Product	I _C = 0.2A; V _{CE} = 10V, f _{test} = 1MHz	10		MHz

Switching Times; Resistive Load

td	Delay Time	I _C = 5A; I _{B1} = -I _{B2} = 1A,V _{CC} = 125V; t _p = 20 μ s, Duty Cycle≪1%	0.1	μ S
tr	Rise Time		0.4	μs
ts	Storage Time		2.5	μs
t _f	Fall Time		0.5	μs

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